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April 1st, 2010 Renesas Electronics Corporation

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DATA SHEET



MOS INTEGRATED CIRCUIT μ PD23C128000BL

128M-BIT MASK-PROGRAMMABLE ROM 16M-WORD BY 8-BIT (BYTE MODE) / 8M-WORD BY 16-BIT (WORD MODE)

Description

The μ PD23C128000BL is a 134,217,728 bits mask-programmable ROM. The word organization is selectable (BYTE mode : 16,777,216 words by 8 bits, WORD mode : 8,388,608 words by 16 bits). With 44-pin PLASTIC SOP package products, only word mode can be used; it is not possible to switch to byte mode.

The active levels of OE (Output Enable Input) can be selected with mask-option.

The µPD23C128000BL is packed in 48-pin PLASTIC TSOP (I) and 44-pin PLASTIC SOP.

Features

Word organization

16,777,216 words by 8 bits (BYTE mode) Note

8,388,608 words by 16 bits (WORD mode) Note

Note With 44-pin PLASTIC SOP package products, only word mode can be used.

It is not possible to switch to byte mode.

• Operating supply voltage : Vcc = 2.7 to 3.6 V

Operating supply voltage	Access time	Power supply current (Active mode)	Standby current (CMOS level input)
Vcc	ns (MAX.)	mA (MAX.)	μΑ (MAX.)
$3.0~V\pm0.3~V$	120	50	30
$3.3~\text{V}\pm0.3~\text{V}$	100	55	

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Document No. M15900EJ4V0DS00 (4th edition) Date Published February 2006 NS CP (K) Printed in Japan

The mark <R> shows major revised points.

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The revised points can be easily searched by copying an "<R>" in the PDF file and specifying it in the "Find what:" field.

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Ordering Information

	Part Number	Package
	μPD23C128000BLGY-xxx-MJH	48-pin PLASTIC TSOP(I) (12x18) (Normal bent)
	μ PD23C128000BLGY-xxx-MKH	48-pin PLASTIC TSOP(I) (12x18) (Reverse bent)
	μPD23C128000BLGX-xxx	44-pin PLASTIC SOP (15.24 mm (600))
<r></r>	μPD23C128000BLGY-xxx-MJH-A	48-pin PLASTIC TSOP(I) (12x18) (Normal bent)
<r></r>	μ PD23C128000BLGY-xxx-MKH-A	48-pin PLASTIC TSOP(I) (12x18) (Reverse bent)
<r></r>	μPD23C128000BLGX-xxx-A	44-pin PLASTIC SOP (15.24 mm (600))

Remarks 1. xxx : ROM code suffix No.

<R>

2. Products with -A at the end of the part number are lead-free products.

Pin Configurations

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/xxx indicates active low signal.

48-pin PLASTIC TSOP (I) (12x18) (Normal bent) [μPD23C128000BLGY-xxx-MJH] [μPD23C128000BLGY-xxx-MJH-A]

	Marking Side	
WORD, /BYTE O	1 48	O GND
	2 47	O GND
	3 46	→→ ⊖ 015, A–1
	4 45	07
A13 O	5 44	O 014
A12 ○	6 43	
A11 ⊖—-►	7 42	O 013
A10 O	8 41	→ ○ 05
A9 O	9 40	→ ○ 012
A8 O	10 39	→ ○ 04
A19 〇——►	11 38	O Vcc
A21 O	12 37	O Vcc
A20 🔿 🗕	13 36	•O A22
A18 〇——►	14 35	→ ○ 011
A17 O►	15 34	→ ○ 03
A7 ⊖►	16 33	→ ○ O10
A6 ⊖	17 32	→ ○ O2
A5 O	18 31	→ ○ O9
A4 O	19 30	→ ○ 01
A3 ()	20 29	→ ○ 08
A2 O	21 28	→ ○ 00
A1 O	22 27	O /OE or OE or DC
A0 O	23 26	O GND
/CE O	24 25	O GND

A0 to A22	:	Address inputs
O0 to O7, O8 to O14	:	Data outputs
O15, A–1	:	Data output 15 (WORD mode),
		LSB Address input (BYTE mode)
WORD, /BYTE	:	Mode select input
/CE	:	Chip Enable input
/OE or OE	:	Output Enable input
Vcc	:	Supply voltage
GND	:	Ground
DC	:	Don't Care

Remark Refer to Package Drawings for the 1-pin index mark.

48-pin PLASTIC TSOP (I) (12x18) (Reverse bent) [μPD23C128000BLGY-xxx-MKH] [μPD23C128000BLGY-xxx-MKH-A]

	Marking Side	
GND O	48 1	- O WORD, /BYTE
GND O	47 2	
015, A–1 ()	46 3	→ A15
07 🕞 🗕	45 4	→ ⊖ A14
014 🖂 🗕	44 5	
06 🔾 🗕	43 6	
013 🔾 🗕	42 7	 → ○ A11
05 🔾 🗕	41 8	
012 🔾 🗕	40 9	→ ○ A9
04 🔾 🗕	39 10	→ → A8
Vcc O	38 11	 →○ A19
Vcc O	37 12	
A22 🔾 🗕	36 13	
011 〇-	35 14	
03 🔾 🗕	34 15	
O10 ⊖ -	33 16	 →○ A7
02 🖂	32 17	
09 〇-	31 18	
01 🔾 🗕	30 19	←───────────────── A4
08 🔾 🗕	29 20	
00 〇-	28 21	→ ○ A2
/OE or OE or DC O	27 22	
	26 23	
GND O	25 24	

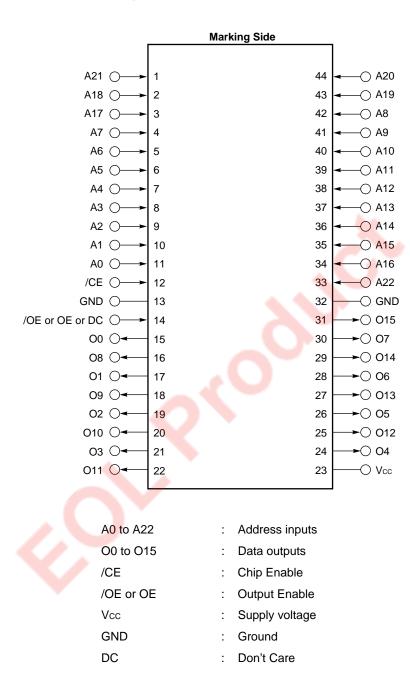
A0 to A22	:	Address inputs
00 to 07, 08 to 014	:	Data outputs
O15, A–1	:	Data output 15 (WORD mode),
		LSB Address input (BYTE mode)
WORD, /BYTE	:	Mode select input
/CE	:	Chip Enable input
/OE or OE	:	Output Enable input
Vcc	:	Supply voltage
GND	:	Ground
DC	:	Don't Care

Remark Refer to **Package Drawings** for the 1-pin index mark.

Data Sheet M15900EJ4V0DS

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44-pin PLASTIC SOP (15.24 mm (600)) [μPD23C128000BLGX-xxx] [μPD23C128000BLGX-xxx-A]



Remarks 1. Refer to Package Drawings for the 1-pin index mark.

 With 44-pin PLASTIC SOP package products, only word mode (8,388,608 words x 16 bits) can be used. There is no mode select (WORD, /BYTE) pin.

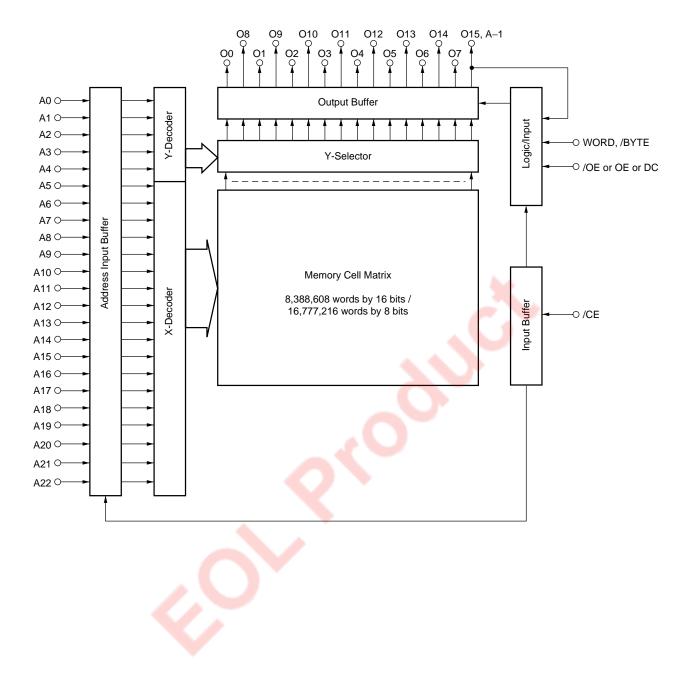
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Input / Output Pin Functions

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Pin name	Input / Output	Function		
WORD, /BYTE	Input	The pin for switching WORD mode and BYTE mode.		
		High level : WORD mode (8M-word by 16-bit)		
		Low level : BYTE mode (16M-word by 8-bit)		
A0 to A22	Input	Address input pins.		
(Address inputs)		A0 to A22 are used differently in the WORD mode and the BYTE mode.		
		WORD mode (8M-word by 16-bit)		
		A0 to A22 are used as 23 bits address signals.		
		BYTE mode (16M-word by 8-bit)		
		A0 to A22 are used as the upper 23 bits of total 24 bits of address signal.		
		(The least significant bit (A–1) is combined to O15.)		
O0 to O7, O8 to O14	Output	Data output pins.		
(Data outputs)		O0 to O7, O8 to O14 are used differently in the WORD mode and the BYTE mode.		
		WORD mode (8M-word by 16-bit)		
		The lower 15 bits of 16 bits data outputs to O0 to O14.		
		(The most significant bit (O15) combined to A-1.)		
		BYTE mode (16M-word by 8-bit)		
		8 bits data outputs to O0 to O7 and also O8 to O14 are high impedance.		
O15, A–1	Output, Input	D15, A-1 are used differently in the WORD mode and the BYTE mode.		
(Data output 15,		WORD mode (8M-word by 16-bit)		
LSB Address input)		The most significant output data bus (O15).		
		BYTE mode (16M-word by 8-bit)		
		The least significant address bus (A–1).		
/CE	Input	Chip activating signal.		
(Chip Enable)		When the OE is active, output states are following.		
		High level : High-Z		
		Low level : Data out		
/OE or OE or DC	Input 🥢	Output enable signal. The active level of OE is mask option. The active level of OE		
(Output Enable, Don't Care)		can be selected from high active, low active and Don't care at order.		
Vcc	-	Supply voltage		
GND		Ground		
<	6			

Block Diagram



NEC

Mask Option

The active levels of output enable pin (/OE or OE or DC) are mask programmable and optional, and can be selected from among " 0 " " 1 " " x " shown in the table below.

Option	/OE or OE or DC	OE active level
0	/OE	L
1	OE	Н
x	DC	Don't care

Operation modes for each option are shown in the tables below.

Operation mode (Option : 0)

/CE	/OE	Mode	Output state
L	L	Active	Data out
	н		High-Z
Н	H or L	Standby	High-Z

Operation mode (Option : 1)

/CE	OE	Mode	Output state
L	L	Active	High-Z
	Н		Data out
Н	H or L	Standby	High-Z

Operation mode (Option : x)

/CE	DC	Mode	Output state
L	H or L	Active	Data out
Н	H or L	Standby	High-Z

Remark L : Low level input

H : High level input

Electrical Specifications

Absolute Maximum Ratings

Parameter	Symbol	Condition	Rating	Unit
Supply voltage	Vcc		-0.3 to +4.6	V
Input voltage	Vı		-0.3 to Vcc+0.3	V
Output voltage	Vo		-0.3 to Vcc+0.3	V
Operating ambient temperature	TA		-10 to +70	°C
Storage temperature	Tstg		-65 to +150	°C

Caution Exposing the device to stress above those listed in Absolute Maximum Ratings could cause permanent damage. The device is not meant to be operated under conditions outside the limits described in the operational section of this specification. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

Capacitance (TA = 25 °C)

Parameter	Symbol	Test condition	MIN.	TYP.	MAX.	Unit
Input capacitance	Сі	f = 1 MHz			10	pF
Output capacitance	Со				12	pF

DC Characteristics (T_A = -10 to +70 °C, V_{cc} = 2.7 to 3.6 V)

Parameter	Symbol	Test condition	MIN.	TYP.	MAX.	Unit	
High level input voltage	Vін			2.0		Vcc + 0.3	V
Low level input voltage	VIL	Vcc = 3.0 V ± 0.3 V		-0.3		+0.5	V
	•	Vcc = 3.3 V ± 0.3 V		-0.3		+0.8	
High level output voltage	Vон	Іон = -100 μA		2.4			V
Low level output voltage	Vol	loL = 2.1 mA				0.4	V
Input leakage current	lu	V ₁ = 0 V to Vcc		-10		+10	μA
Output leakage current	ILO	Vo = 0 V to Vcc, Chip deselected		-10		+10	μA
Power supply current	Icc1	/CE = VIL (Active mode), Vcc = $3.0 \text{ V} \pm 0.3 \text{ V}$				50	mA
		$I_{O} = 0 \text{ mA} \qquad \qquad V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$				55	
Standby current	Іссз	/CE = Vcc - 0.2 V (Standby mode)				30	μA

AC Characteristics (TA = -10 to +70 °C, Vcc = 2.7 to 3.6 V)

Parameter	Symbol	Test condition	$\text{Vcc} = 3.0 \text{ V} \pm 0.3 \text{ V}$		$\text{Vcc} = 3.3 \text{ V} \pm 0.3 \text{ V}$			Unit	
			MIN	TYP.	MAX.	MIN	TYP.	MAX.	
Address access time	tacc				120			100	ns
Address skew time	t skew	Note			10			10	ns
Chip enable access time	tce				120			100	ns
Output enable access time	toe				25			25	ns
Output hold time	tон		0			0			ns
Output disable time	tdf		0		20	0		20	ns
WORD, /BYTE access time	twв				120			100	ns

Note tskew indicates the following three types of time depending on the condition.

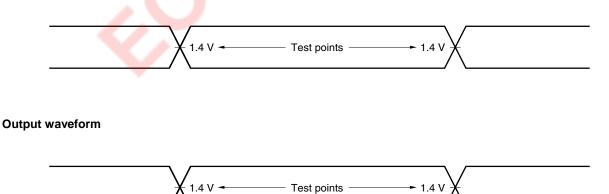
- 1) When switching /CE from high level to low level, tskew is the time from the /CE low level input point until the next address is determined.
- 2) When switching /CE from low level to high level, tskew is the time from the address change start point to the /CE high level input point.
- 3) When /CE is fixed to low level, tskew is the time from the address change start point until the next address is determined.

Since specs are defined for tskew only when /CE is active, tskew is not subject to limitations when /CE is switched from high level to low level following address determination, or when the address is changed after /CE is switched from low level to high level.

Remark tor is the time from inactivation of Chip Enable input (/CE) or Output Enable input (/OE or OE) to high impedance state output.

AC Test Conditions

Input waveform (Rise / Fall Time ≤ 5 ns)



Output load

1TTL + 100 pF

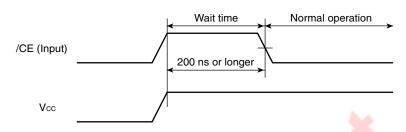
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Cautions on power application

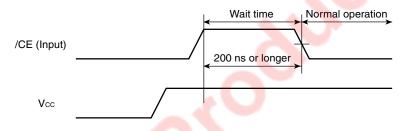
To ensure normal operation, always apply power using /CE following the procedure shown below.

- 1) Input a high level to /CE during and after power application.
- 2) Hold the high level input to /CE for 200 ns or longer (wait time).
- 3) Start normal operation after the wait time has elapsed.

Power Application Timing Chart 1 (When /CE is made high at power application)



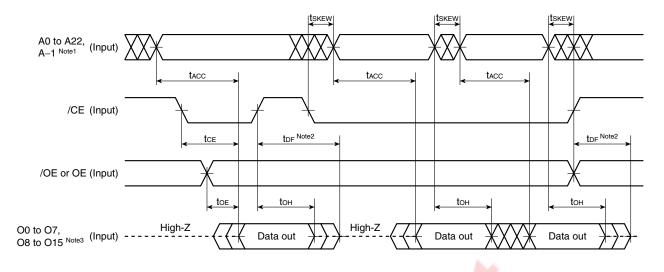
Power Application Timing Chart 2 (When /CE is made high after power application)



Caution Other signals can be either high or low during the wait time.

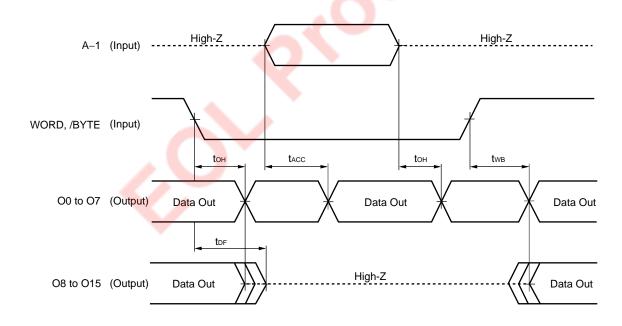
Read Cycle Timing Chart

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Notes 1. During WORD mode, A–1 is O15.

- 2. tDF is the time from inactivation of Chip Enable input (/CE) or Output Enable input (/OE or OE) to high impedance state output.
- 3. During BYTE mode, O8 to O14 are high impedance and O15 is A-1.

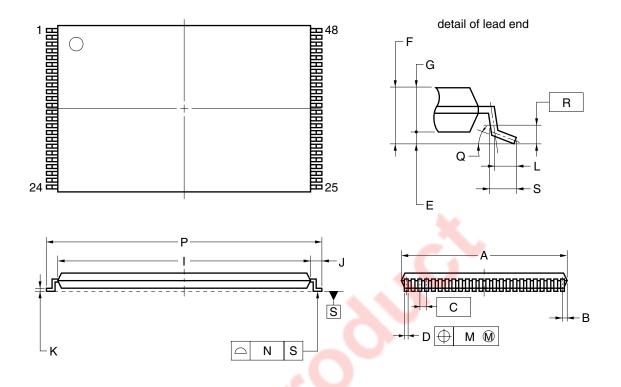


WORD, /BYTE Switch Timing Chart

Remark Chip Enable (/CE) and Output Enable (/OE or OE) : Active.

Package Drawings

48-PIN PLASTIC TSOP(I) (12x18)

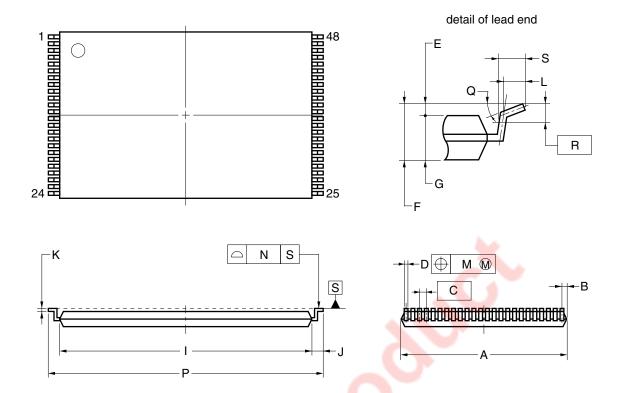


NOTES

- 1. Each lead centerline is located within 0.10 mm of its true position (T.P.) at maximum material condition.
- 2. "A" excludes mold flash. (Includes mold flash : 12.4 mm MAX.)

ITEM	MILLIMETERS
А	12.0±0.1
В	0.45 MAX.
С	0.5 (T.P.)
D	0.22±0.05
Е	0.1±0.05
F	1.2 MAX.
G	1.0±0.05
I	16.4±0.1
J	0.8±0.2
к	0.145±0.05
L	0.5
М	0.10
Ν	0.10
Р	18.0±0.2
Q	$3^{\circ}^{+5^{\circ}}_{-3^{\circ}}$
R	0.25
S	0.60±0.15
5	648GY-50-MJH1-1

48-PIN PLASTIC TSOP(I) (12x18)

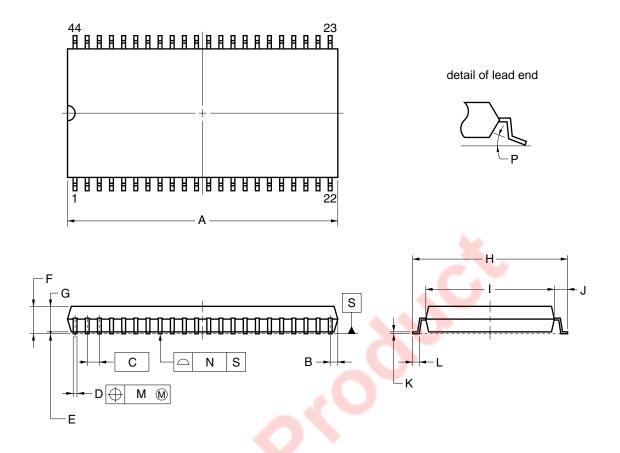


NOTES

- 1. Each lead centerline is located within 0.10 mm of its true position (T.P.) at maximum material condition.
- 2. "A" excludes mold flash. (Includes mold flash : 12.4 mm MAX.)

ITEM	MILLIMETERS
А	12.0±0.1
В	0.45 MAX.
С	0.5 (T.P.)
D	0.22±0.05
Е	0.1±0.05
F	1.2 MAX.
G	1.0±0.05
I	16.4±0.1
J	0.8±0.2
К	0.145±0.05
L	0.5
М	0.10
Ν	0.10
Р	18.0±0.2
Q	3° ^{+5°} 3°
R	0.25
S	0.60±0.15
S	648GY-50-MKH1-1

44-PIN PLASTIC SOP (15.24 mm (600))



NOTE

Each lead centerline is located within 0.12 mm of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS
А	27.83 ^{+0.4} -0.05
В	0.78 MAX.
С	1.27 (T.P.)
D	$0.42\substack{+0.08\\-0.07}$
E	0.15±0.1
F	3.0 MAX.
G	2.7±0.05
Н	16.04±0.3
1	13.24±0.1
J	1.4±0.2
к	$0.22\substack{+0.08\\-0.07}$
L	0.8±0.2
М	0.12
N	0.10
Р	3° ^{+7°} -3°
	P44GX-50-600A-4

Recommended Soldering Conditions

Please consult with our sales offices for soldering conditions of the μ PD23C128000BL.

Types of Surface Mount Device

	μPD23C128000BLGY-xxx-MJH	: 48-pin PLASTIC TSOP(I) (12x18) (Normal bent)
	μPD23C128000BLGY-xxx-MKH	: 48-pin PLASTIC TSOP(I) (12x18) (Reverse bent)
	μPD23C128000BLGX-xxx	: 44-pin PLASTIC SOP (15.24 mm (600))
<r></r>	μPD23C128000BLGY-xxx-MJH-A	: 48-pin PLASTIC TSOP(I) (12x18) (Normal bent)
<r></r>	μPD23C128000BLGY-xxx-MKH-A	: 48-pin PLASTIC TSOP(I) (12x18) (Reverse bent)
<r></r>	μPD23C128000BLGX-xxx-A	: 44-pin PLASTIC SOP (15.24 mm (600))

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Revision History

Edition/	Page		Type of	Location	Description
Date	This Previous		revision		(Previous edition \rightarrow This edition)
	edition	edition			
4th edition/	p.2	p.1	Addition	Ordering Information	Lead-free products have been added
Feb. 2006	pp.3-5	pp.2-4	Addition	Pin Configuration	Lead-free products have been added
	p.16	p.15	Addition	Recommended Soldering	Lead-free products have been added
				Conditions	

[MEMO]

NEC

– NOTES FOR CMOS DEVICES –

1 VOLTAGE APPLICATION WAVEFORM AT INPUT PIN

Waveform distortion due to input noise or a reflected wave may cause malfunction. If the input of the CMOS device stays in the area between V_{IL} (MAX) and V_{IH} (MIN) due to noise, etc., the device may malfunction. Take care to prevent chattering noise from entering the device when the input level is fixed, and also in the transition period when the input level passes through the area between V_{IL} (MAX) and V_{IH} (MIN).

(2) HANDLING OF UNUSED INPUT PINS

Unconnected CMOS device inputs can be cause of malfunction. If an input pin is unconnected, it is possible that an internal input level may be generated due to noise, etc., causing malfunction. CMOS devices behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using pull-up or pull-down circuitry. Each unused pin should be connected to V_{DD} or GND via a resistor if there is a possibility that it will be an output pin. All handling related to unused pins must be judged separately for each device and according to related specifications governing the device.

③ PRECAUTION AGAINST ESD

A strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it when it has occurred. Environmental control must be adequate. When it is dry, a humidifier should be used. It is recommended to avoid using insulators that easily build up static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work benches and floors should be grounded. The operator should be grounded using a wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with mounted semiconductor devices.

④ STATUS BEFORE INITIALIZATION

Power-on does not necessarily define the initial status of a MOS device. Immediately after the power source is turned ON, devices with reset functions have not yet been initialized. Hence, power-on does not guarantee output pin levels, I/O settings or contents of registers. A device is not initialized until the reset signal is received. A reset operation must be executed immediately after power-on for devices with reset functions.

5 POWER ON/OFF SEQUENCE

In the case of a device that uses different power supplies for the internal operation and external interface, as a rule, switch on the external power supply after switching on the internal power supply. When switching the power supply off, as a rule, switch off the external power supply and then the internal power supply. Use of the reverse power on/off sequences may result in the application of an overvoltage to the internal elements of the device, causing malfunction and degradation of internal elements due to the passage of an abnormal current.

The correct power on/off sequence must be judged separately for each device and according to related specifications governing the device.

(6) INPUT OF SIGNAL DURING POWER OFF STATE

Do not input signals or an I/O pull-up power supply while the device is not powered. The current injection that results from input of such a signal or I/O pull-up power supply may cause malfunction and the abnormal current that passes in the device at this time may cause degradation of internal elements. Input of signals during the power off state must be judged separately for each device and according to related specifications governing the device.

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